

1. General description

Planar passivated sensitive gate four quadrant triac in a SOT78 (TO-220AB) plastic package intended for use in general purpose bidirectional switching and phase control applications. This sensitive gate "series E" triac is intended to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

2. Features and benefits

- Direct triggering from low power drivers and logic ICs
- High blocking voltage capability
- · Planar passivated for voltage ruggedness and reliability
- Sensitive gate
- Triggering in all four quadrants

3. Applications

- General purpose motor control
- General purpose switching

4. Quick reference data

| Table 1. Qu | ick reference data | | | | | | |
|---------------------|--|---|--|-----|-----|-----|------|
| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
| V _{DRM} | repetitive peak off- state voltage | | | - | - | 800 | V |
| I _{TSM} | non-repetitive peak on- state current | full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4; Fig. 5</u> | | - | - | 95 | A |
| Tj | junction temperature | | | - | - | 125 | °C |
| I _{T(RMS)} | RMS on-state current | full sine wave; T _{mb} ≤ 99 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u> | | - | - | 12 | A |
| Static charac | teristics | | | | | | |
| I _{GT} | gate trigger current | V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u> | | - | 2.5 | 10 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u> | | - | 4 | 10 | mA |





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| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|---------------------|-----------------------------------|--|-----|-----|-----|------|
| | | $V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; \text{ T2- G-};$ $T_j = 25 \text{ °C}; \frac{\text{Fig. 7}}{7}$ | - | 5 | 10 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G+; T _j = 25 °C; <u>Fig. 7</u> | - | 11 | 25 | mA |
| Dynamic chara | acteristics | | | | | |
| dV _D /dt | rate of rise of off-state voltage | V_{DM} = 536 V; T_j = 125 °C; (V_{DM} = 67% of V_{DRM}); exponential waveform; gate open circuit | - | 150 | - | V/µs |

5. Pinning information

| Table 2. | Pinning | information | | |
|----------|---------|-----------------------------------|--------------------|----------------|
| Pin | Symbol | Description | Simplified outline | Graphic symbol |
| 1 | T1 | main terminal 1 | mb | T2 |
| 2 | T2 | main terminal 2 | | Sym051 |
| 3 | G | gate | | |
| mb | T2 | mounting base; main terminal 2 | | |
| | | | TO-220AB (SOT78) | |

6. Ordering information

Table 3.Ordering information

| Type number | Package | | |
|---------------|----------|--|---------|
| | Name | Description | Version |
| BT138-800E | TO-220AB | plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB | SOT78 |
| BT138-800E/DG | TO-220AB | plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB | SOT78 |

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7. Limiting values

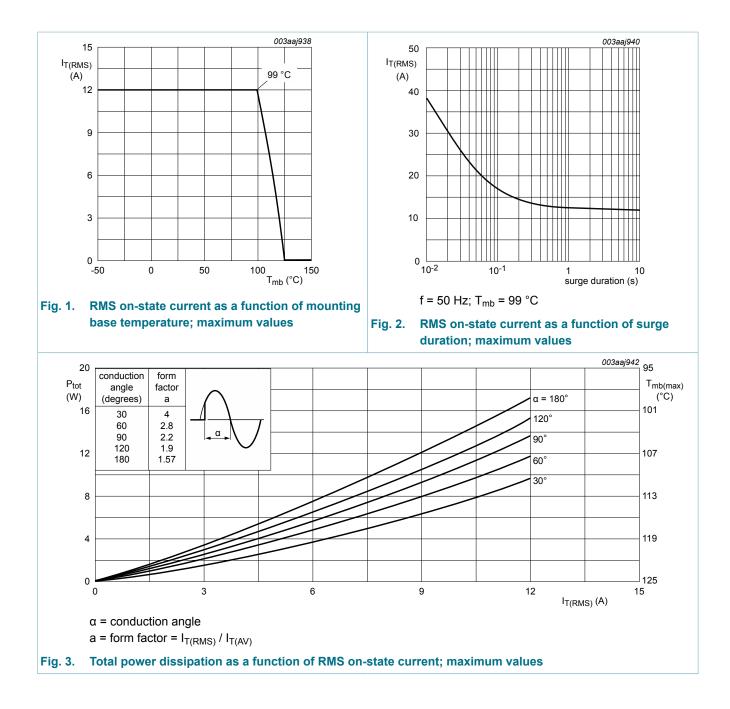
Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------------|--------------------------------------|--|-----|-----|------------------|
| V _{DRM} | repetitive peak off-state voltage | | - | 800 | V |
| I _{T(RMS)} | RMS on-state current | full sine wave; $T_{mb} \le 99$ °C; Fig. 1; Fig. 2; Fig. 3 | - | 12 | A |
| I _{TSM} | non-repetitive peak on-state current | full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 20 \text{ ms}; Fig. 4; Fig. 5$ | - | 95 | A |
| | | full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms | - | 105 | A |
| l ² t | I ² t for fusing | t _p = 10 ms; sine-wave pulse | - | 45 | A ² s |
| dI _T /dt | rate of rise of on-state current | I_T = 20 A; I_G = 0.2 A; dI_G/dt = 0.2 A/µs; T2+ G+ | - | 50 | A/µs |
| | | I_T = 20 A; I_G = 0.2 A; dI_G/dt = 0.2 A/µs; T2+ G- | - | 50 | A/µs |
| | | I_T = 20 A; I_G = 0.2 A; dI_G/dt = 0.2 A/µs; T2- G- | - | 50 | A/µs |
| | | I _T = 20 A; I _G = 0.2 A; dI _G /dt = 0.2 A/μs; T2- G+ | - | 10 | A/µs |
| I _{GM} | peak gate current | | - | 2 | А |
| P _{GM} | peak gate power | | - | 5 | W |
| P _{G(AV)} | average gate power | over any 20 ms period | - | 0.5 | W |
| T _{stg} | storage temperature | | -40 | 150 | °C |
| Tj | junction temperature | | - | 125 | °C |

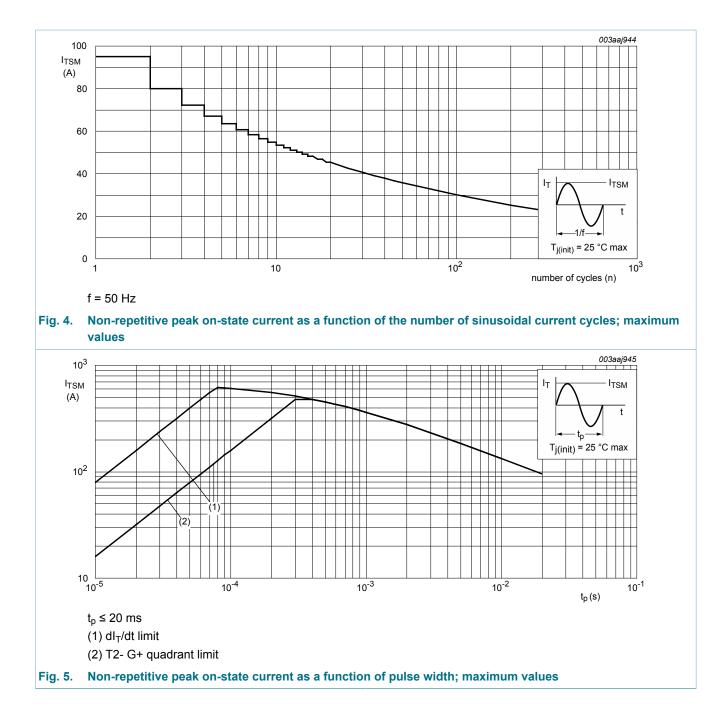
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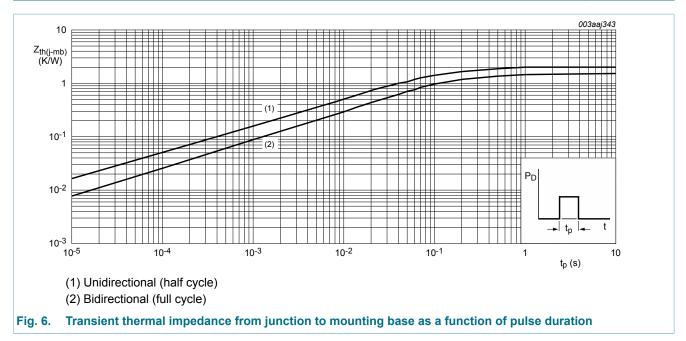
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8. Thermal characteristics

| Table 5. The | ermal characteristics | | | | | |
|-----------------------|---|--------------------|-----|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| R _{th(j-mb)} | thermal resistance | full cycle; Fig. 6 | - | - | 1.5 | K/W |
| | from junction to mounting base | half cycle; Fig. 6 | - | - | 2 | K/W |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | - | 60 | - | K/W |



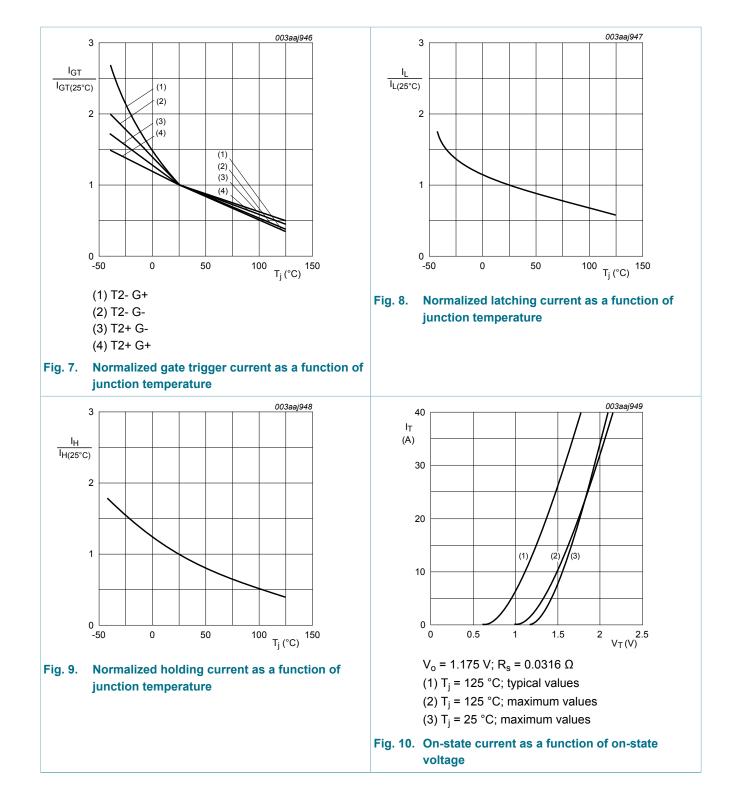
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9. Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|---------------------|-----------------------------------|--|---------|-----|------|------|
| Static chara | acteristics | | · · · · | | | |
| I _{GT} | gate trigger current | V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u> | - | 2.5 | 10 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u> | - | 4 | 10 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u> | - | 5 | 10 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G+; T _j = 25 °C; <u>Fig. 7</u> | - | 11 | 25 | mA |
| L | latching current | V _D = 12 V; I _G = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 8</u> | - | - | 30 | mA |
| | | V_D = 12 V; I _G = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 8</u> | - | - | 40 | mA |
| | | $V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2- G-};$ T _j = 25 °C; Fig. 8 | - | - | 30 | mA |
| | | $V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2- G+};$ T _j = 25 °C; Fig. 8 | - | - | 40 | mA |
| н | holding current | V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u> | - | - | 30 | mA |
| / _T | on-state voltage | I _T = 15 A; T _j = 25 °C; <u>Fig. 10</u> | - | 1.4 | 1.65 | V |
| / _{GT} | gate trigger voltage | V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 11 | - | 0.7 | 1 | V |
| | | V _D = 400 V; I _T = 0.1 A; T _j = 125 °C; Fig. 11 | 0.25 | 0.4 | - | V |
| D | off-state current | V _D = 800 V; T _j = 125 °C | - | 0.1 | 0.5 | mA |
| Dynamic cl | naracteristics | · · · · · · · · · · · · · · · · · · · | I | | | |
| dV _D /dt | rate of rise of off-state voltage | V_{DM} = 536 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit | - | 150 | - | V/µs |
| lgt | gate-controlled turn-on time | I _{TM} = 16 A; V _D = 800 V; I _G = 0.1 A; dI _G / dt = 5 A/μs | - | 2 | - | μs |

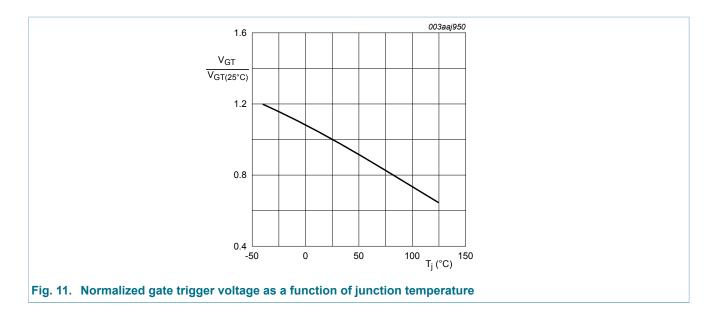
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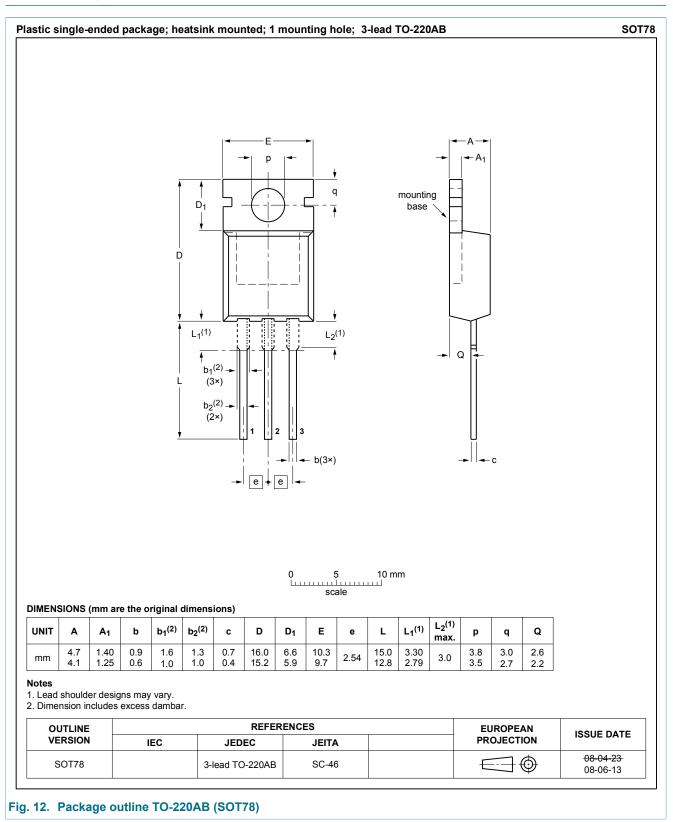


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10. Package outline



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| Document status [1][2] | Product status [3] | Definition |
|--------------------------------------|-----------------------|---|
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